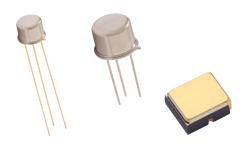


PNP Radiation Hardened Amplifier

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Features

- Available in JAN, JANTX, JANTXV and JANS per MIL-PRF-19500/357
- Ideal for General Purpose Switching and Amplifier Applications
- Available in TO-5, TO-39, UB and UBN packages



Electrical Characteristics

Parameter	Test Conditions	Symbol	Units	Min.	Max.
Off Characteristics		<u>'</u>	'	<u>'</u>	
Collector - Base Cutoff Current Voltage	V_{CB} = 140 V dc 2N3634, L, UB, UBN V_{CB} = 140 V dc 2N3635, L, UB, UBN V_{CB} = 175 V dc 2N3636, L, UB, UBN V_{CB} = 175 V dc 2N3637, L, UB, UBN	I _{CBO1}	μA dc	_	10
Collector - Emitter Breakdown Voltage	I _C = 10 mA dc 2N3634, L, UB, UBN 2N3635, L, UB, UBN 2N3636, L, UB, UBN 2N3637, L, UB, UBN	V _{(BR)CEO}	V dc	140 140 175 175	_
Collector - Base Cutoff Current	V _{CB} = 100 V dc	I _{CBO2}	nA dc	_	100
Emitter - Base Cutoff Current	V _{EB} = 5 V dc	I _{EBO1}	μA dc	_	10
Emitter - Base Cutoff Current	V _{EB} = 3 V dc	I _{EBO2}	nA dc		50
Collector - Emitter Cutoff Current	V _{CE} = 100 V dc	I _{CEO}	μA dc		10
On Characteristics ¹					
	V _{CE} = 10 V dc, I _C = 0.1 mA dc 2N3634, L, UB, UBN 2N3636, L, UB, UBN 2N3635, L, UB, UBN 2N3637, L, UB, UBN	h _{FE1}		25 55	
Forward Current Transfer Ratio	V_{CE} = 10 V dc, I_{C} = 1.0 mA dc 2N3634, L, UB, UBN 2N3636, L, UB, UBN	h _{FE2}	_	45	
	2N3635, L, UB, UBN 2N3637, L, UB, UBN $V_{CE} = 10 \text{ V dc, } I_{C} = 10 \text{ mA dc}$ $2N3634, L, UB, UBN$ $2N3636, L, UB, UBN$	h _{FE3}		90 50	
	2N3635, L, UB, UBN 2N3637, L, UB, UBN			100	

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On Characteristics ¹					
Forward Current Transfer Ratio	V _{CE} = 10 V dc, I _C = 50 mA dc 2N3634, L, UB, UBN 2N3636, L, UB, UBN 2N3635, L, UB, UBN 2N3637, L, UB, UBN V _{CE} = 10 V dc, I _C = 150 mA dc 2N3634, L, UB, UBN 2N3636, L, UB, UBN 2N3635, L, UB, UBN 2N3637, L, UB, UBN	h _{FE4}	-	50 100 30 60	150 300
Collector - Emitter Voltage (saturated)	I_C = 10 mA dc, I_B = 1 mA dc I_C = 50 mA dc, I_B = 5 mA dc	V _{CE(SAT)1}	V dc	_	0.3 0.6
Base - Emitter Voltage (saturated)	I_{C} = 10 mA dc, I_{B} = 1.0 mA dc I_{C} = 50 mA dc, I_{B} = 5.0 mA dc	V _{BE(SAT)1}	Vdc	0.65	0.8 0.90
Collector-Base Cutoff Current	T _A = +150°C V _{CB} = -100 V dc	I _{CBO3}	μA dc		10
Forward-Current Transfer Ratio	$T_A = -55^{\circ}\text{C}$ $V_{CE} = 10 \text{ V dc}, I_C = 50 \text{ mA dc}$ $2\text{N}3634, \text{ L}, \text{ UB}, \text{ UBN}$ $2\text{N}3636, \text{ L}, \text{ UB}, \text{ UBN}$ $2\text{N}3635, \text{ L}, \text{ UB}, \text{ UBN}$ $2\text{N}3637, \text{ L}, \text{ UB}, \text{ UBN}$	h _{FE6}	25 50		



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Electrical Characteristics

Parameter	Test Conditions	Symbol	Units	Min.	Max.	
Dynamic Characteristics						
	V_{CE} = 30 V dc, I_{C} = 30 mA dc, f = 100 MHz 2N3634, L, UB, UBN			4.5	8.0	
Small-Signal Short-Circuit, Forward-Current Transfer Ratio	2N3636, L, UB, UBN 2N3635, L, UB, UBN	h _{FE}	-	1.5		
	2N3637, L, UB, UBN			2.0	8.5	
	$V_{CE} = 10 \text{ V dc}, I_{C} = 10 \text{ mA dc}, f = 1 \text{ kHz}$					
Small-Signal Short-Circuit, Forward-Current Transfer Ratio	2N3634, L, UB, UBN 2N3636, L, UB, UBN	h _{FE}	-	40	160	
	2N3635, L, UB, UBN 2N3637, L, UB, UBN			80	320	
	V_{CE} = 10 V dc, I_C = 10 mA dc, f = 1 kHz					
Small-Signal Short-Circuit Input Impedance	2N3634, L, UB, UBN 2N3636, L, UB, UBN	h _{ie}	Ω	100	600	
	2N3635, L, UB, UBN 2N3637, L, UB, UBN			200	1200	
Small-Signal Open Circuit Reverse Voltage Transfer Ratio	V_{CE} = 10 V dc, I_{C} = 10 mA dc, f = 1 kHz	h _{re}			3x10 ⁻⁴	
Small-Signal Open Circuit Output Admittance	$V_{CE} = 10 \text{ V dc}, I_{C} = 10 \text{ mA dc}, f = 1 \text{ kHz}$	h _{oe}	μs		200	
Open Circuit Output Capacitance	$V_{CB} = 20 \text{ V dc}, I_E = 0, 100 \text{ kHz} \le f \le 1 \text{ MHz}$	C _{obo}	pF	_	10	
Input Capacitance (Output Open Circuited)	$V_{EB} = 1 \text{ V dc}, I_C = 0, 100 \text{ kHz} \le f \le 1 \text{ MHz}$	C _{ibo}	pF	_	75	
Noise Figure	V_{CE} = 10 V dc, I_{C} = 0.5 mA dc, R_{G} = 1 k Ω , f = 100 Hz, f = 10 kHz, f = 1 kHz	NF	dB	_	5 3 3	



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Absolute Maximum Ratings ($T_A = +25^{\circ}C$ unless otherwise specified)

Thermal Characteristics	Symbol	Max. Value
Thermal Resistance, Junction to Ambient 2N3634, 2N3634L 2N3635, 2N3635L 2N3636, 2N3636L 2N3637, 2N3637L	R _{θJA} ⁽⁴⁾	175°C/W
Thermal Resistance, Junction to Ambient 2N3634UB, UBN 2N3635UB, UBN 2N3636UB, UBN 2N3637UB, UBN	R _{θJA} ⁽⁴⁾	325°C/W
Thermal Resistance, Junction to Case 2N3634, 2N3634L 2N3635, 2N3635L 2N3636, 2N3636L 2N3637, 2N3637L	R _{θJC} ⁽⁴⁾	35°C/W
Thermal Resistance, Junction to Solder Pad 2N3634UB, UBN 2N3635UB, UBN 2N3636UB, UBN 2N3637UB, UBN	R _{eJSP} (4)	90°C/W

⁽⁴⁾ See figures 10, 11, and 12 of MIL-PRF-19500/357



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Absolute Maximum Ratings (T_A = +25°C unless otherwise specified)

Characteristics	Symbol	Max. Value
T _A = +25°C 2N3634, 2N3634L 2N3635, 2N3635L 2N3636, 2N3636L 2N3637, 2N3637L	P _T ⁽¹⁾	1W
T _A = +25°C 2N3634UB, UBN 2N3635UB, UBN 2N3636UB, UBN 2N3637UB, UBN	P _T ⁽¹⁾	0.5 W
T _C = +25°C 2N3634, 2N3634L 2N3635, 2N3635L 2N3636, 2N3636L 2N3637, 2N3637L	P _T ⁽²⁾	5W
T _{SP} = +25°C 2N3634UB, UBN 2N3635UB, UBN 2N3636UB, UBN 2N3637UB, UBN	P _T ⁽³⁾	1.5W

⁽¹⁾ See figure 6 and 7 of MIL-PRF-19500/357

⁽²⁾ See figure 8 of MIL-PRF-19500/357

⁽³⁾ See figure 9 of MIL-PRF-19500/357



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Absolute Maximum Ratings (T_A = +25°C unless otherwise specified)

Ratings	Symbol	Value
Collector - Emitter Voltage 2N3634, 2N3635 2N3636, 2N3637	V _{CEO}	140 V dc 175 V dc
Collector - Base Voltage 2N3634, 2N3635 2N3636, 2N3637	V _{CBO}	140 V dc 175 V dc
Emitter - Base Voltage	V _{EBO}	5 V dc
Collector Current	I _C	1 A dc
Operating & Storage Temperature Range	T _J , T _{STG}	-65°C to +200°C

Switching Characteristics	Test Conditions	Symbol			Max Value
Pulse Delay Time	See Figure 13 of MIL-PRF-19500/357	t_{d}	ns	_	100
Pulse Rise Time	See Figure 13 of MIL-PRF-19500/357	t _r	ns	_	100
Pulse Storage Time	See Figure 13 of MIL-PRF-19500/357	ts	ns	_	500
Pulse Fall Time	See Figure 13 of MIL-PRF-19500/357	t _f	ns	_	150
t _{off}	t _s & t _f	t _{off}	ns	_	600

Safe Operating Area

DC Tests: TO-39 T_{C} = +25°C, I Cycle, t = 1.0 s

Test 1:

2N3634, 2N3634L $V_{CE} = 100 \text{ V dc}, I_{C} = 30 \text{ mA dc}$

2N3635, 2N3635L

2N3636, 2N3636L V_{CE} = 130 V dc, I_{C} = 20 mA dc

2N3637, 2N3637L

 V_{CE} = 50 V dc, I_{C} = 95 mA dc Test 2: Test 3: V_{CE} = 5 V dc, I_{C} = 1 A dc

DC Tests: UB $T_C = +25$ °C, I Cycle, t = 100 ms

Test 1:

 V_{CE} = 85 V dc, I_{C} = 30 mA dc 2N3634UB, 2N3635UB

2N3634UBN, 2N3635UBN

2N3636UB, 2N3637UB V_{CE} = 125 V dc, I_{C} = 20 mA dc

2N3636BN, 2N3637UBN

 V_{CE} = 50 V dc, I_{C} = 50 mA dc Test 2:

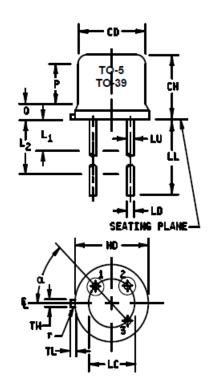
Test 3: $V_{CE} = 5 \text{ V dc}, I_{C} = 500 \text{ mA dc}$



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Outline Drawings TO-5, TO-39

	Dimensions				
Ltr	Inc	hes	Millimeters		Notes
	Min	Max	Min	Max	
CD	.305	.335	7.75	8.51	
CH	.240	.260	6.10	6.60	
HD	.335	.370	8.51	9.40	
LC	.200	TYP	5.08	TYP	7
LD	.016	.021	0.41	0.53	6
LL	S	ee notes	7, 9, and	10	
LU	.016	.019	0.41	0.48	7
L ₁		.050		1.27	7
L ₂	.250		6.35		7
Р	.100		2.54		5
Q		.050		1.27	
r		.010		0.254	8
TL	.029	.045	0.74	1.14	4
TW	.028	.034	0.71	0.86	3
α	45° TP 45° TP				6
Term 1	Emitter				
Term 2	Base				
Term 3	Collector				



NOTES:

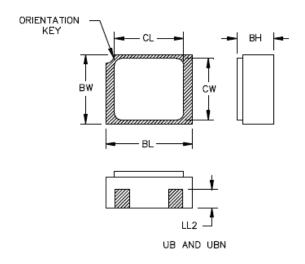
- Dimensions are in inches.
- 2. Millimeters are given for general information only.
- Beyond r maximum, TW must be held to a minimum length of .021 inch (0.53 mm).
- TL measured from maximum HD.
- 5. CD shall not vary more than ±.010 inch (0.25 mm) in zone P. This zone is controlled for automatic handling.
- Leads at gauge plane .054 .055 inch (1.37 1.40 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at a maximum material condition (MMC) relative to the tab at MMC. The device may be measured by direct methods or by gauge and gauging procedure.
- LU applies between L₁ and L₂. LD applies between L₂ and L minimum. Diameter is uncontrolled in L₁ and beyond LL minimum.
- 8. r (radius) applies to both inside corners of tab.
- For transistor types 2N3634 through 2N3637, LL is .500 inch (12.70 mm) minimum, and .750 inch (19.05 mm) maximum (TO-39).
- For transistor types 2N3634L through 2N3637L, LL is 1.500 inches (38.10 mm) minimum, and 1.750 inches (44.45 mm) maximum (TO-5).
- 11. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

FIGURE 1. Physical dimensions (TO-5 and TO-39).



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Outline Drawings UB, UBN



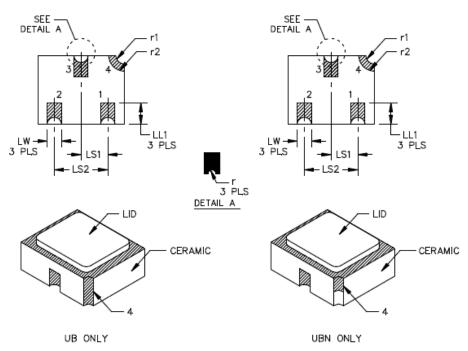


FIGURE 2. Physical dimensions, surface mount 2N3634UB through 2N3637UB (UB and UBN version).



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